

INTELLECTUAL PROPERTY 402-391-4448 16-04-04

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10328 PINEHURST AVE. OMAHA, NEBRASKA 68124

October 1, 2004

Parsons Hsue and De LLP 655 Montogomery St. San Francisco, CA 94111

RE: OPPOSITION TO PUBLISHED APPLICATION OF NIKOONAHAD ET AL.

TITLED "OPTICAL SYSTEM FOR MEASURING SAMPLES USING SHORT

WAVELENGTH RADIATION"; SERIAL NO.: 10/718,126; FILE DATE: NOV. 19, 2003; PUB. NO.: US2004/0150820.

Dear Sirs;

Enclosed please find copies of materials we feel should be considered by the Examiner during Prosecution of the identified case, and which have been provided to the Patent Office.

Sincerely,

TAMES D. WELCH

JŴ/hs enc.



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PROFESSIONAL ENGINEER

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October 1, 2004

Commissioner for Patents

Box: 1450

Alexandria, AV 22313-1450

RE: OPPOSITION TO PUBLISHED APPLICATION OF NIKOONAHAD ET AL.

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Dear Sir;

Please find enclosed a Check for \$180.00 and Ten (10) Publications which we feel the Examiner should consider in the Examination.

ARTICLES:

"OPTICAL METROLOGY ROADMAP FOR THE SEMICONDUCTOR, OPTICAL AND DATA STORAGE INDUSTRIES", WOOLLAM ET AL., PROC. OF SPIE., VOL 4099, (JULY 2000).

"SPECTROSCOPIC ELLIPSOMETRY FROM THE VACUUM ULTRAVIOLET TO THE FAR INFRARED:, WOOLLAM ET AL., CHARACTERIZATION AND METROLOGY FOR ULSI TECHNOLOGY: 2000 INTERNATIONAL CONFERENCE.

"CHARACTERIZATION OF THIN FILMS AND MULTILAYERS IN THE VUV WAVELENGTH RANGE USING SPECTROSCOPIC ELLIPSOMETRY AND SPECTROSCOPIC PHOTOMETRY", BOHER ET AL., 157 NM SYMPOSIUM, (MAY 2000).

"MATERIALS CHARACTERIZATION IN THE VACUUM ULTRAVIOLET WITH VARIABLE ANGLE SPECTROSCOPIC ELLIPSOMETRY", WAGNER ET AL., PHYS. STAT. SOL. (a) 188, no. 4, (2001).

"SPECTROSCOPIC ELLIPSOMETRY IN TEH VACUUM ULTRAVIOLET: 157 NM AND BELOW", HILFIKER ET AL., (AND RELATED MATERIALS), FUTURE FAB INTERNATIONAL, (2000).

"157 NM RESIST MATERIALS: PROGRESS REPORT", BRODSKY ET AL., J. VAC. SCI. TECHNOL. B 18(6) (NOV/DEC 2000).

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"IN SITU MONITORING OF GAN METAL-ORGANIC VAPOR PHASE EPITAXY BY SPECTROSCOPIC ELLIPSOMETRY", PETERS, J. APP. PHYS., VOL. 88, NO. 7, (OCT. 2000).

"ORDINARY AND EXTRAORDINARY DIELECTRIC FUNCTIONS OF 4H- AND 6H-SIC FROM 3.5 TO 9.0 EV", LINDQUIST ET AL., APP. PHYS. LETT., VOL 78, NO. 18 (APR. 2001).

"PRECISE CHARACTREIZATIONM OF RESISTS AND THIN GATE DIELECTRICS IN THE VUV RANGE FOR 157 NM LITHOGRAPHY", BOJER ET AL., MAT. RES. SOC. SYMP., VOL 636, (2001).

"FLUOROPOLYMERS FOR 157-NM LITHOGRAPHY: OPTICAL PROPERTIES FROM VUV ABSORBANCE AND ELLIPSOMETRY MEASUREMENTS", FRENCE ET AL., PROC. SPIE, VOL 4000, (JUL. 2000).

I attest that a copy of the accompanying materials was sent to Applicant's Attorney: Parsons Hsue and De LLP, at 655 Montogomery St., San Francisco, CA 94111 with First Class Postage affixed on October 1, 2004.

Sinderely,

JAMES D. WELCH

JW//hs enc.